

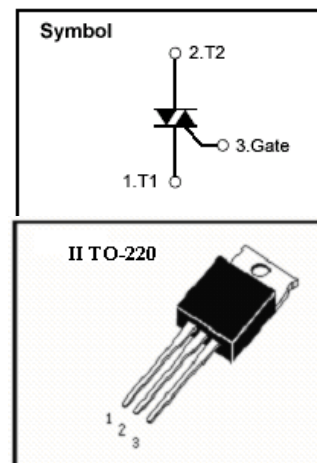
主要用途

内部绝缘型双向可控硅，用于电源控制、马达控制、温度控制、照明控制、复印机等。

极限值 ($T_a=25^{\circ}\text{C}$)

T_s, t_g ——贮存温度.....	-40~125 $^{\circ}\text{C}$
T_j ——结温.....	-40~125 $^{\circ}\text{C}$
P_{GM} —— 峰值门极功耗.....	5 W
V_{DRM} ——重复峰值断态电压.....	600V
$I_T (RMS)$ ——RMS 通态电流 ($T_c=68^{\circ}\text{C}$)	16A
V_{GM} ——峰值门极电压.....	10V
I_{GM} —— 峰值门极电流.....	2.0A
I_{TSM} ——浪涌通态电流(1 个周期,50/60Hz,峰值,不重复).....	155/170A
V_{iso} ——RMS 绝缘电压.....	2500V

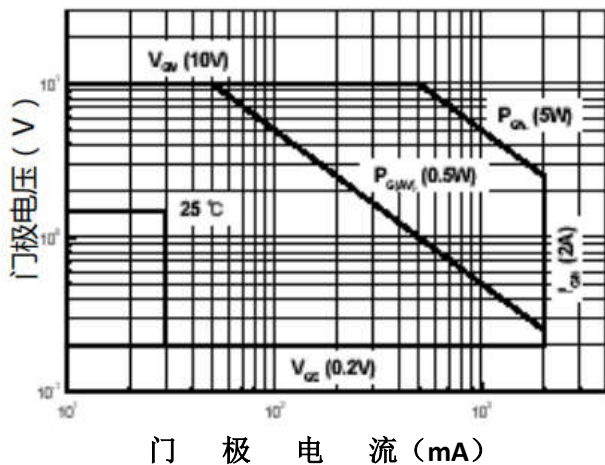
外形图及引脚排列



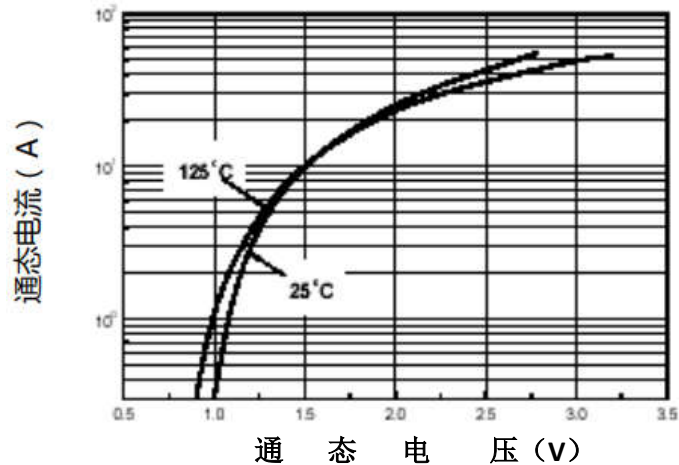
参数符号	符 号 说 明	最小值	典型值	最大值	单 位	测 试 条 件
I_{DRM}	重复峰值断态电流			2.0	mA	$V_D=V_{DRM}$, 单相, 半波, $T_J=125^{\circ}\text{C}$
V_{TM}	峰值通态电压			1.4	V	$I_T=25\text{A}$, 快速测量
I_{+GT1}	门极触发电流 (I)			30	mA	$V_D=6\text{V}$, $R_L=10\text{ ohm}$
I_{-GT1}	门极触发电流 (II)			30	mA	$V_D=6\text{V}$, $R_L=10\text{ ohm}$
I_{-GT3}	门极触发电流 (III)			30	mA	$V_D=6\text{V}$, $R_L=10\text{ ohm}$
V_{+GT1}	门极触发电压 (I)			1.5	V	$V_D=6\text{V}$, $R_L=10\text{ ohm}$
V_{-GT1}	门极触发电压 (II)			1.5	V	$V_D=6\text{V}$, $R_L=10\text{ ohm}$
V_{-GT3}	门极触发电压 (III)			1.5	V	$V_D=6\text{V}$, $R_L=10\text{ ohm}$
V_{GD}	不触发门极电压	0.2			V	$T_J=125^{\circ}\text{C}$, $V_D=1/2V_{DRM}$
$(dv/dt)_c$	断态电压临界上升率	10.0			V/ μS	$T_J=125^{\circ}\text{C}$, $V_D=2/3V_{DRM}$ $(di/dt)_c=-8.0\text{A/ms}$
$R_{th(j-c)}$	热阻			3.0	$^{\circ}\text{C/W}$	结到外壳
I_H	维持电流		25		mA	

特性曲线

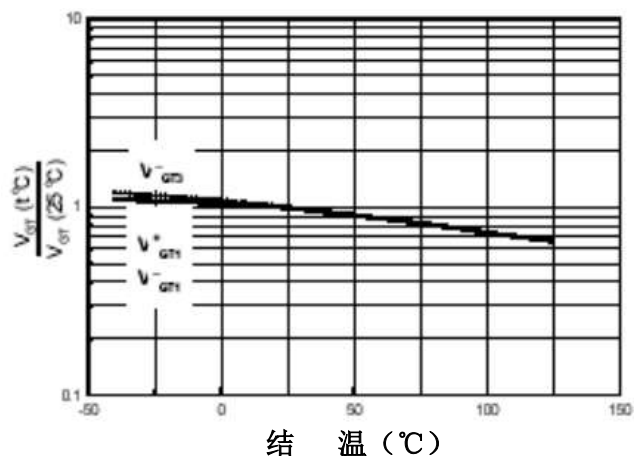
图一、门极特性



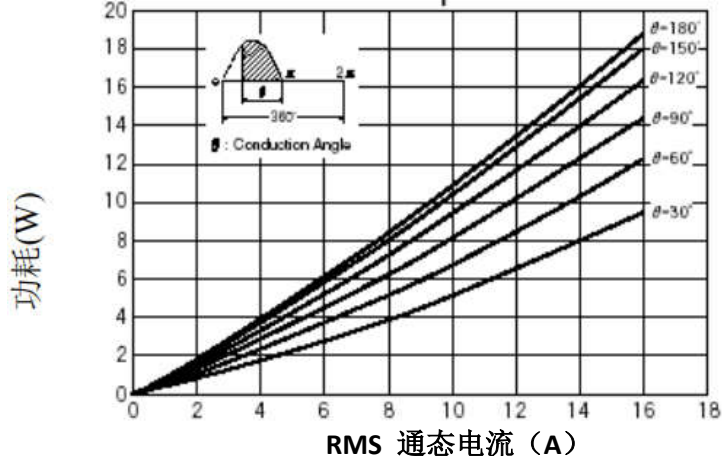
图二、通态电压



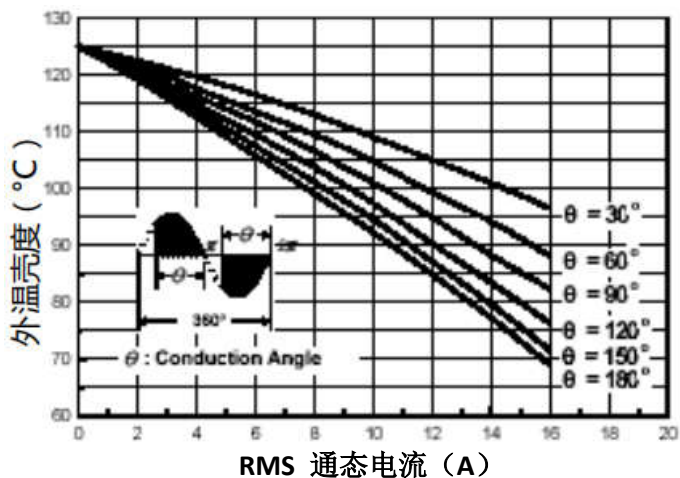
图三、门极触发电压-----结温



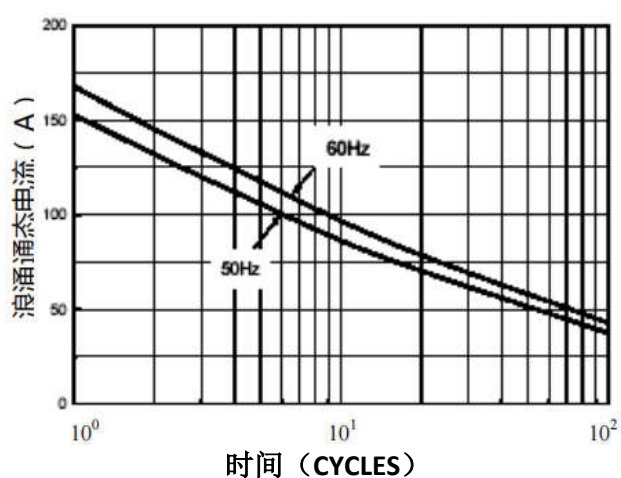
图四、通态电流---最大功耗



图五、通态电流---外壳温度

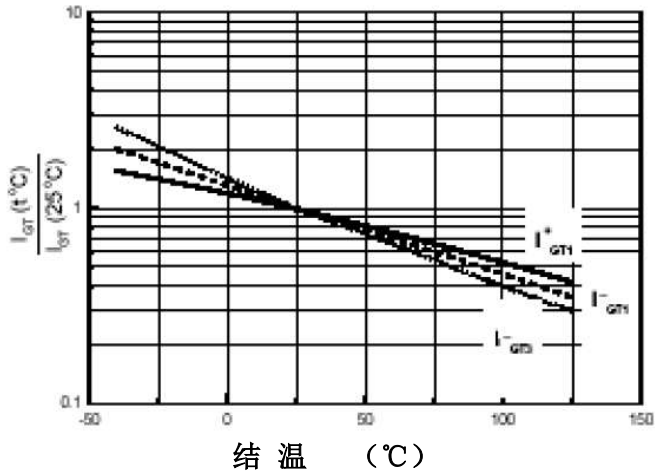


图六、浪涌通态最大电流（不重复）

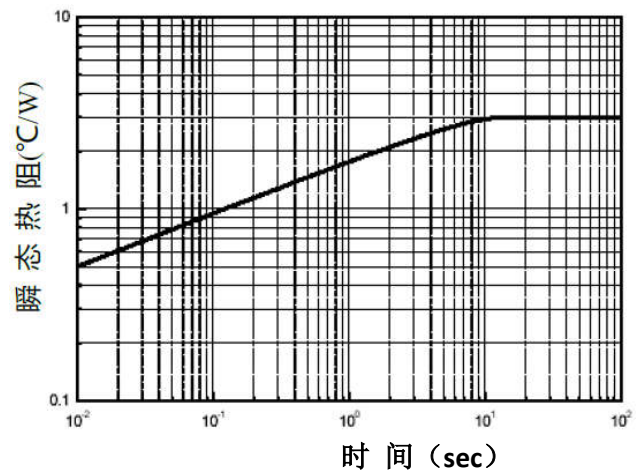


特性曲线

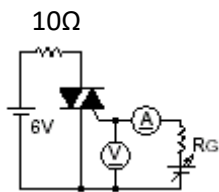
图七、门极触发电流---结温



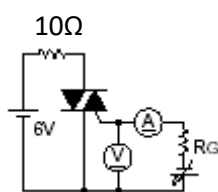
图八、瞬态热阻



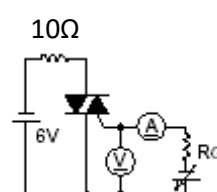
图九、门极触发特性测试电路



测试方式 I



测试方式 II



测试方式 III



迈诺斯科技

BTA16-600B

NOTE:

1. Exceeding the maximum ratings of the device in performance may cause damage to the device, even the permanent failure, which may affect the dependability of the machine. Please do not exceed the absolute maximum ratings of the device when circuit designing.
2. When installing the heat sink, please pay attention to the torsional moment and the smoothness of the heat sink.
3. MOSFETs is the device which is sensitive to the static electricity, it is necessary to protect the device from being damaged by the static electricity when using it.
4. Shenzhen Minos reserves the right to make changes in this specification sheet and is subject to change without prior notice.

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